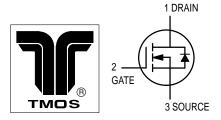
TMOS FET Switching

N-Channel — Enhancement



BS170



MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|-------------------------------------|-------------|------------|
| Drain-Source Voltage | V _{DS} | 60 | Vdc |
| Gate–Source Voltage — Continuous — Non–repetitive (t _p ≤ 50 μs) | V _{GS} V _{GSM} | ±20 ±40 | Vdc Vpk |
| Drain Current ⁽¹⁾ | ID | 0.5 | Adc |
| Total Device Dissipation @ T _A = 25°C | PD | 350 | mW |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|---------------------|-----|------|-----|-------|
| OFF CHARACTERISTICS | | | | | • |
| Gate Reverse Current (V _{GS} = 15 Vdc, V _{DS} = 0) | IGSS | _ | 0.01 | 10 | nAdc |
| Drain–Source Breakdown Voltage (V _{GS} = 0, I _D = 100 μAdc) | V(BR)DSS | 60 | 90 | _ | Vdc |
| ON CHARACTERISTICS(2) | | | | | • |
| Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 1.0 mAdc) | VGS(Th) | 0.8 | 2.0 | 3.0 | Vdc |
| Static Drain–Source On Resistance (V _{GS} = 10 Vdc, I _D = 200 mAdc) | rDS(on) | _ | 1.8 | 5.0 | Ω |
| Drain Cutoff Current (V _{DS} = 25 Vdc, V _{GS} = 0 Vdc) | ^I D(off) | _ | _ | 0.5 | μА |
| Forward Transconductance (V _{DS} = 10 Vdc, I _D = 250 mAdc) | 9fs | _ | 200 | _ | mmhos |
| SMALL-SIGNAL CHARACTERISTICS | | | | | • |
| Input Capacitance (V _{DS} = 10 Vdc, V _{GS} = 0, f = 1.0 MHz) | C _{iSS} | _ | _ | 60 | pF |
| SWITCHING CHARACTERISTICS | | | | | |
| Turn-On Time (I _D = 0.2 Adc) See Figure 1 | t _{on} | _ | 4.0 | 10 | ns |
| Turn-Off Time (I _D = 0.2 Adc) See Figure 1 | ^t off | _ | 4.0 | 10 | ns |

- 1. The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

RESISTIVE SWITCHING

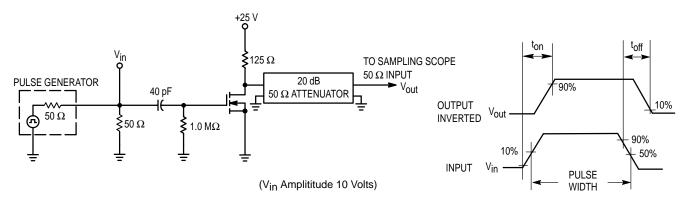


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

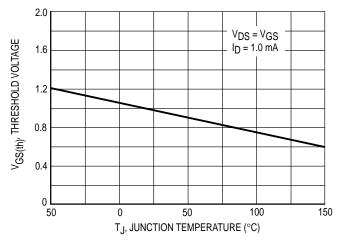


Figure 3. V_{GS(th)} Normalized versus Temperature

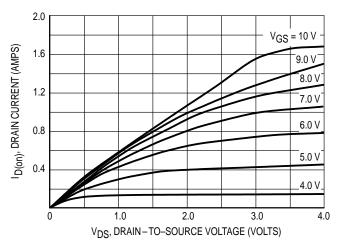


Figure 4. On-Region Characteristics

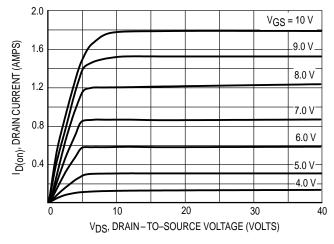


Figure 5. Output Characteristics

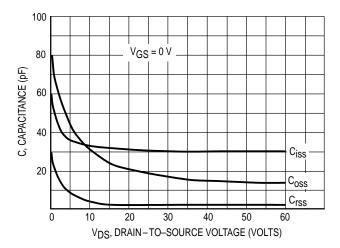
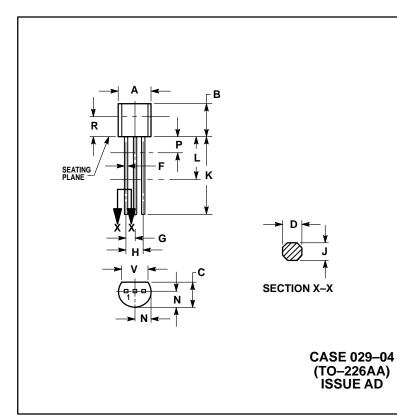


Figure 6. Capacitance versus Drain-To-Source Voltage

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. DIMENSION FAPPLIES BETWEEN P AND L. DIMENSION D AND J. APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INCHES | | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.175 | 0.205 | 4.45 | 5.20 |
| В | 0.170 | 0.210 | 4.32 | 5.33 |
| С | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.022 | 0.41 | 0.55 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| Н | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | | 12.70 | |
| L | 0.250 | | 6.35 | |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| Р | | 0.100 | | 2.54 |
| R | 0.115 | | 2.93 | |
| ٧ | 0.135 | | 3.43 | |

- STYLE 30:
 PIN 1. DRAIN
 2. GATE
 3. SOURCE

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